## HA13408

## 9-Channel Power Driver HITACHI

## Description

The HA13408 9-channel power driver IC is designed to drive dot matrix printer head. This IC can drive 9 pins without using any external components. HA13408 can be used for 2 system four-phase step drive, as every channel is used independently.

## Features

- High output current: 1.5 A/channel Max
- High sustaining voltage: 50 V Min
- Low saturation voltage
- Low supply current
- Low input current
- Compatible with TTL, LSTTL \& 5 V CMOS
- Low thermal resistance package
- Zener diodes


## Truth Table

| Input | Output |
| :--- | :--- |
| Low | On |
| High | Off |
| Open | Off |

## Block Diagram



## Peak Current and Turn-Off Time

Figure 1 shows load current (Iout) and output terminal voltage (Vout) waveforms for the HA13408 driving an inductive load.


Figure 1 Output Waveforms
The peak output current (Ip) and sustain time (tsus) are obtained as follows;

$$
\begin{align*}
& I_{P}=\frac{V_{C C 2}-V_{C E(\text { sat) }}}{R}\left(1-\exp \left(-\frac{R}{L} t_{\text {on }}\right)\right) \doteqdot \frac{V_{C C 2}}{R}\left(1-\exp \left(-\frac{R}{L} t_{\text {on }}\right)\right)  \tag{1}\\
& t_{\text {sus }}=\frac{L}{R} \ln \left(1+\frac{I_{P} \cdot R}{V_{C E(\text { sus })}-V_{C C 2}}\right) \tag{2}
\end{align*}
$$

Where L is load self-inductance and R is load direct current resistance.
For example, under the following conditions:
$\mathrm{L}=5 \mathrm{mH}$,
$\mathrm{R}=22 \Omega$
Supply voltage $\mathrm{V}_{\mathrm{CC} 2}=24 \mathrm{~V}$,
Time to drive load ton $=0.42 \mathrm{~ms}$.
Peak current (Ip) and sustain time (tsus) are then:

$$
\mathrm{I}_{\mathrm{P}}=0.87 \mathrm{~A}
$$

## HA13408

$$
\mathrm{t}_{\mathrm{sus}}=0.118 \mathrm{~ms}
$$

Where $\mathrm{V}_{\mathrm{CE}(\text { sat })}=1.3 \mathrm{~V}$ typ and $\mathrm{V}_{\mathrm{CE}(\text { sus })}=52 \mathrm{~V}$ typ.

## Power Dissipation

Power dissipation driving an inductive load for an HA13408 is determined as follows:
First, average power dissipation (Pon) per channel at ton is obtained as follows:

$$
\begin{equation*}
\text { Pon } \doteqdot \mathrm{V}_{\mathrm{CE}(\text { sat) })} \mathrm{I}_{\mathrm{P}}\left(\frac{\mathrm{~V}_{\mathrm{CC} 2}}{\mathrm{R} \cdot \mathrm{I}_{\mathrm{P}}}-\frac{1}{\mathrm{t}_{\text {on }}} \frac{\mathrm{L}}{\mathrm{R}}\right) \tag{3}
\end{equation*}
$$

Average power dissipation (Psus) at $\mathrm{t}_{\text {sus }}$ :

$$
\begin{equation*}
\text { Psus } \doteqdot \mathrm{V}_{\mathrm{CE}(\text { sus })} I_{P}\left(\frac{1}{t_{\text {sus }}} \frac{\mathrm{L}}{\mathrm{R}}-\frac{\mathrm{V}_{\mathrm{CE}(\text { sus })}-\mathrm{V}_{\mathrm{CC2}}}{R \cdot I_{P}}\right) \tag{4}
\end{equation*}
$$

Where $I_{p}$ and tsus are obtained in equations (1) and (2).
Average power dissipation $\left(\mathrm{P}_{\mathrm{T}}\right)$ per channel for a period is obtained as follows:

$$
\begin{equation*}
\mathrm{P}_{\mathrm{T}} \doteqdot \frac{1}{\mathrm{~T}}\left(\text { Pon } \cdot \mathrm{t}_{\text {on }}+\text { Psus } \cdot \mathrm{t}_{\text {sus }}\right) \tag{5}
\end{equation*}
$$

Where drive period is defined as T .
Power dissipation $\left(\mathrm{P}_{\mathrm{T}}\right)$ for 9 channels driven at the same time:

$$
\begin{equation*}
\mathrm{P}_{\mathrm{T}} \doteqdot \frac{9}{\mathrm{~T}}\left(\text { Pon } \cdot \mathrm{t}_{\mathrm{on}}+\text { Psus } \cdot \mathrm{t}_{\text {sus }}\right) \tag{6}
\end{equation*}
$$

## Application



Figure 2 Dot Matrix Printer

Absolute Maximum Ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Item | Symbol | Rating | Unit | Notes |
| :--- | :--- | :--- | :--- | :--- |
| Supply voltage | $\mathrm{V}_{\mathrm{CC} 1}$ | 7.0 | V |  |
| Input voltage | $\mathrm{V}_{1}$ | $\mathrm{~V}_{\mathrm{CC} 1}$ | V |  |
| Output voltage | $\mathrm{V}_{\mathrm{CE}(\text { (sus })}$ | 50 | V |  |
| Output current | $\mathrm{I}_{\mathrm{O}}$ | 1.5 | A |  |
| Power dissipation | $\mathrm{P}_{\mathrm{T}}$ | 20 | W | 1 |
| Junction temperature | Tj | 150 | ${ }^{\circ} \mathrm{C}$ |  |
| Operating junction temperature range | Tjop | -20 to +125 | ${ }^{\circ} \mathrm{C}$ |  |
| Storage temperature range | Tstg | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |  |

Notes: 1. Thermal resistance $\quad \theta_{\mathrm{j}-\mathrm{a}} \leq 40^{\circ} \mathrm{C} / \mathrm{W}$

$$
\theta_{\mathrm{j}-\mathrm{c}} \leq 3^{\circ} \mathrm{C} / \mathrm{W}
$$

Electrical Characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{CC} 1}=5 \mathrm{~V}\right)$

| Item | Symbol Min |  | Typ | Max | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input Low voltage | $\mathrm{V}_{1}$ | - | - | 0.8 | V | $\mathrm{V}_{\mathrm{cC} 1}=4.0 \mathrm{~V}$ |  |
| Input High voltage | $\mathrm{V}_{\text {IH }}$ | 2.0 | - | - | V | $\mathrm{V}_{\mathrm{CC} 1}=6.0 \mathrm{~V}$ |  |
| Input Low current | $1 /$ | -100 | -15 | +10 | $\mu \mathrm{A}$ | $\mathrm{V}_{1}=0 \mathrm{~V}$ |  |
| Input HIgh current | $\mathrm{I}_{\mathrm{H}}$ | -10 | 0 | +10 | $\mu \mathrm{A}$ | $\mathrm{V}_{1}=2.4 \mathrm{~V}$ |  |
| Supply current | $\mathrm{I}_{\text {coo }}$ | - | 30 | 45 | mA | All $\mathrm{V}_{1}=2.4 \mathrm{~V}$ |  |
|  | $\mathrm{I}_{\mathrm{cc}}$ | - | 33 | 50 | mA | All $\mathrm{V}_{1}=0 \mathrm{~V}$ |  |
| Output cut off current | $\mathrm{I}_{\text {CEO }}$ | - | - | 1.0 | mA | $\mathrm{V}_{\mathrm{CC} 1}=6 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC2}}=40 \mathrm{~V}, \mathrm{~V}_{1}=2.0 \mathrm{~V}$ |  |
| Output saturation voltage | $\mathrm{V}_{\text {CE(sat) }}$ | - | 1.6 | 2.2 | V | $\mathrm{V}_{\text {CC } 1}=4 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=1.0 \mathrm{~A}, \mathrm{~V}_{1}=0.8 \mathrm{~V}$ |  |
| Output sustaining voltage | $\mathrm{V}_{\mathrm{CE} \text { (sus) }}$ | 50 | - | - | V | $\mathrm{I}_{0}=1.0 \mathrm{~A}$ | 1 |
| Delay time | $\mathrm{t}_{\text {PLH }}$ | - | 1.5 | 5 | $\mu \mathrm{s}$ | Turn OFF |  |
|  | $\mathrm{t}_{\text {PHL }}$ | - | 0.3 | 5 | $\mu \mathrm{s}$ | Turn ON |  |

Note: 1. The conditions of loading; Measure at $\mathrm{Ls}=5 \mathrm{mH}, \mathrm{Rs}=22 \Omega$.

## Package Dimensions

Unit: mm


| Hitachi Code | SP-23TA |
| :--- | :--- |
| JEDEC | - |
| EIAJ | - |
| Weight (reference value) | 4.61 g |

## Cautions

1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
5. This product is not designed to be radiation resistant.
6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

## HITACHI

## Hitachi, Ltd.

Semiconductor \& Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109
URL NorthAmerica : http:semiconductor.hitachi.com/

Asia (Singapore)
Asia (Taiwan)
Asia (HongKong) Japan
: http://www.hitachi-eu.com/hel/ecg
http://www.has.hitachi.com.sg/grp3/sicd/index.htm
http://www.hitachi.com.tw/E/Product/SICD_Frame.htm
http://www.hitachi.com.hk/eng/bo/grp3/index.htm
http://www.hitachi.co.jp/Sicd/indx.htm

## For further information write to:

Hitachi Semiconductor
America) Inc.
179 East Tasman Drive, San Jose,CA 95134
Tel: <1> (408) 433-1990
Fax: <1>(408) 433-0223

Hitachi Europe GmbH
Electronic components Group Dornacher Stra§e 3
D-85622 Feldkirchen, Munich Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9293000
Hitachi Europe Ltd Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay \#20-00 Hitachi Tower Singapore 049318
Tel: 535-2100
Fax: 535-1533
Hitachi Asia Ltd.
Taipei Branch Office
3F, Hung Kuo Building. No.167,
Tun-Hwa North Road, Taipei (105)
Tel: <886> (2) 2718-3666
Fax: <886> (2) 2718-8180

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.

This datasheet has been download from:
www.datasheetcatalog.com
Datasheets for electronics components.

